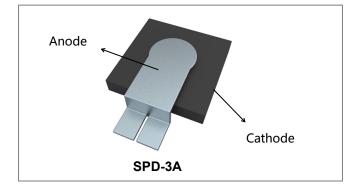


## 120SPC045A

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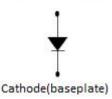


# Power Surface Mount Schottky Rectifier (45V, 120Amp)



#### **Schematic & Pin Configuration**

#### Anode(top leadframe)



#### Features

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- Base plate: Pure Sn plated; Terminals: Pure Sn plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Applications

- Switching power supply
- Redundant power subsystems
- Reverse battery protection
- Converters
- Many other high current AC/DC power supplies

#### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Rectified Forward Current	IF (AV)	50% duty cycle @T <sub>c</sub> =116°C, rectangular wave form	120	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1650	А
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	T <sub>J</sub> =25℃,I <sub>AS</sub> =11A, L=1.2mH	76	mJ
Repetitive Avalanche Current	lar	$I_{AS}$ decaying linearly to 0 in 1 $\mu$ sec Frequency limited by T_J max. V_A=1.5 $\timesV_R$	11	A

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#### **Electrical Characteristics:**

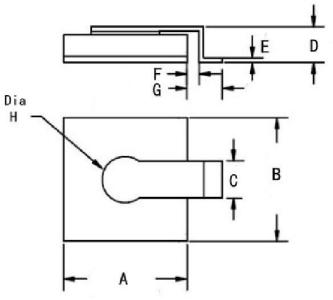
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.58	0.60	V
	V <sub>F2</sub>	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.54	0.57	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ , Pulse, T <sub>J</sub> = 25 °C	0.3	9.0	mA
	I <sub>R2</sub>	$@V_R = rated V_R$ , Pulse, T <sub>J</sub> = 125 °C	66	420	mA
Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	4333	4800	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 µs, duty cycle < 2%

#### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	0.20	°C/W

#### Mechanical Dimensions (Inches/Millimeters)



SYMBOL	Millimeters		Inches		
STIVIDUL	Min.	Max.	Min.	Max.	
A	11.08	11.78	0.436	0.464	
В	11.08	11.78	0.436	0.464	
С	4.93	5.23	0.194	0.206	
D	2.57	3.37	0.101	0.133	
E	0.20	0.60	0.008	0.024	
F	1.02		0.040		
G	4.52		0.178		
н	5.59		0.220		



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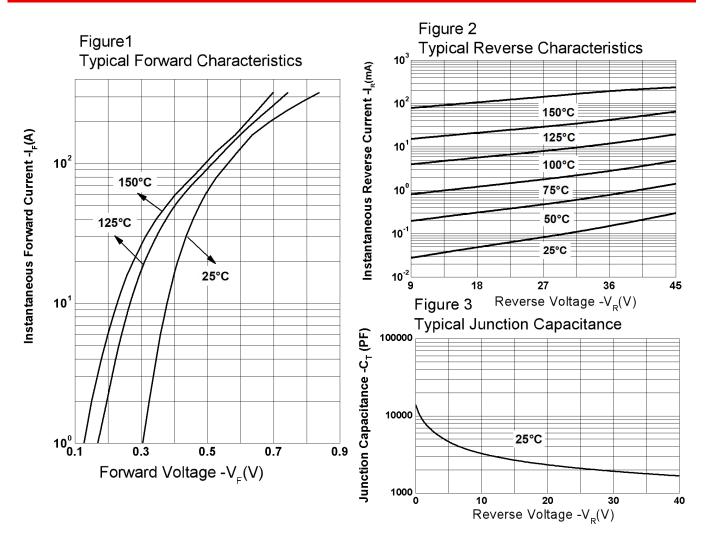


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#### **Ratings and Characteristics Curves**



#### **Ordering Information**

Device	Package	Shipping
120SPC045A	SPD-3A(Pb-Free)	100pcs/ box

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